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# 80-M3126TA150M7-K829F71 datasheet

MiniSKiiP® PACK 3

1200 V / 150 A

## Features

- IGBT M7 technology with low VCEsat and improved EMC behavior
- Tandem diodes for improved thermal performance
- Solder-free spring contact technology

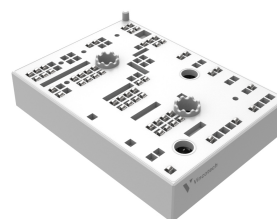
## Target applications

- Elevator Drives
- Embedded Drives
- Servo Drives

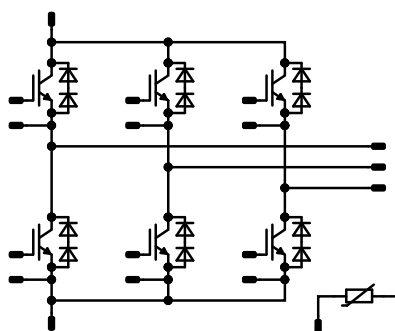
## Types

- 80-M3126TA150M7-K829F71

## MiniSKiiP® 3 16 mm housing



## Schematic





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## Maximum Ratings

$T_j = 25\text{ °C}$ , unless otherwise specified

Parameter	Symbol	Conditions	Value	Unit
<b>Inverter Switch</b>				
Collector-emitter voltage	$V_{CES}$		1200	V
Collector current (DC current)	$I_C$	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	180	A
Repetitive peak collector current	$I_{CRM}$	$t_p$ limited by $T_{jmax}$	300	A
Total power dissipation	$P_{tot}$	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	376	W
Gate-emitter voltage	$V_{GES}$		$\pm 20$	V
Maximum junction temperature	$T_{jmax}$		175	°C

## Inverter Diode

Peak repetitive reverse voltage	$V_{RRM}$		1300	V
Forward current (DC current)	$I_F$	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	98	A
Repetitive peak forward current	$I_{FRM}$	$t_p$ limited by $T_{jmax}$	300	A
Total power dissipation	$P_{tot}$	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	251	W
Maximum junction temperature	$T_{jmax}$		175	°C

## Module Properties

### Thermal Properties

Storage temperature	$T_{stg}$		-40...+125	°C
Operation temperature under switching condition	$T_{jop}$		-40...+( $T_{jmax} - 25$ )	°C

### Isolation Properties

Isolation voltage	$V_{isol}$	DC Test Voltage* $t_p = 2\text{ s}$	5500	V
Isolation voltage	$V_{isol}$	AC Voltage $t_p = 1\text{ min}$	2500	V
Creepage distance		With std lid For more informations see handling instructions	6,3	mm
Clearance		With std lid For more informations see handling instructions	6,3	mm
Comparative Tracking Index	CTI		$\geq 600$	

\*100 % tested in production



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## Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
			$V_{GE}$ [V] $V_{GS}$ [V]	$V_{CE}$ [V] $V_{DS}$ [V] $V_F$ [V]	$I_C$ [A] $I_D$ [A] $I_F$ [A]	$T_j$ [°C]	Min	Typ	Max	

### Inverter Switch

#### Static

Gate-emitter threshold voltage	$V_{GE(th)}$			10	0,015	25	5,4	6	6,6	V
Collector-emitter saturation voltage	$V_{CE(sat)}$		15		150	25 125 150		1,63 1,81 1,86	1,9 <sup>(1)</sup>	V
Collector-emitter cut-off current	$I_{CES}$		0	1200		25			200	µA
Gate-emitter leakage current	$I_{GES}$		20	0		25			1000	nA
Internal gate resistance	$r_g$							2		Ω
Input capacitance	$C_{ies}$	0	10		25			32000		pF
Output capacitance	$C_{oes}$							960		pF
Reverse transfer capacitance	$C_{res}$							380		pF
Gate charge	$Q_g$	$V_{CC} = 600$ V	15		150	25		1140		nC

#### Thermal

Thermal resistance junction to sink <sup>(2)</sup>	$R_{th(j-s)}$	$\lambda_{paste} = 2,5$ W/mK (HPTP)						0,25		K/W
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#### Dynamic

Turn-on delay time	$t_{d(on)}$	$R_{gon} = 4$ Ω $R_{goff} = 4$ Ω	±15	600	150	25 125 150		362,88 367,36 367,68		ns
Rise time	$t_r$					25 125 150		86,72 96,96 100,48		ns
Turn-off delay time	$t_{d(off)}$					25 125 150		275,52 309,44 318,08		ns
Fall time	$t_f$					25 125 150		67,91 92,9 99,19		ns
Turn-on energy (per pulse)	$E_{on}$	$Q_{tFWD}=2,1$ µC $Q_{tFWD}=5,43$ µC $Q_{tFWD}=6,47$ µC				25 125 150		12,32 16,43 17,46		mWs
Turn-off energy (per pulse)	$E_{off}$					25 125 150		11,25 15,38 16,75		mWs



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## Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
			$V_{GE}$ [V] $V_{GS}$ [V]	$V_{CE}$ [V] $V_{DS}$ [V] $V_F$ [V]	$I_C$ [A] $I_D$ [A] $I_F$ [A]	$T_j$ [°C]	Min	Typ	Max	

### Inverter Diode

#### Static

Forward voltage	$V_F$				150	25 125 150		3,19 3,1 3,03	3,84 <sup>(1)</sup>	V
Reverse leakage current	$I_R$	$V_i = 1300$ V				25			7,6	μA

#### Thermal

Thermal resistance junction to sink <sup>(2)</sup>	$R_{th(j-s)}$	$\lambda_{paste} = 2,5$ W/mK (HPTP)						0,38		K/W
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#### Dynamic

Peak recovery current	$I_{RRM}$	$di/dt=1381$ A/μs $di/dt=1141$ A/μs $di/dt=1108$ A/μs	$\pm 15$	600	150	25 125 150		27,94 46,18 49,38		A
Reverse recovery time	$t_{rr}$					25 125 150		105,83 151,36 168,53		ns
Recovered charge	$Q_r$					25 125 150		2,1 5,43 6,47		μC
Reverse recovered energy	$E_{rec}$					25 125 150		0,5 1,41 1,74		mWs
Peak rate of fall of recovery current	$(di_{rr}/dt)_{max}$					25 125 150		2275 2066 1436		A/μs



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## Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
			$V_{GE}$ [V] $V_{GS}$ [V]	$V_{CE}$ [V] $V_{DS}$ [V] $V_F$ [V]	$I_C$ [A] $I_D$ [A] $I_F$ [A]	$T_j$ [°C]	Min	Typ	Max	

## Thermistor

### Static

Rated resistance	$R$					25		1		kΩ
Deviation of $R_{100}$	$\Delta_{R/R}$	$R_{100} = 1670 \Omega$				100	-2		2	%
Maximum Current	$I_{max}$							3		mA
Power dissipation constant	$d$					25		0,76		mW/K
A-value	$A$							$7,635 \times 10^{-3}$		1/K
B-value	$B$							$1,73 \times 10^{-5}$		1/K <sup>2</sup>
Vincotech Thermistor Reference									E	

<sup>(1)</sup> Value at chip level

<sup>(2)</sup> Only valid with pre-applied Vincotech thermal interface material.



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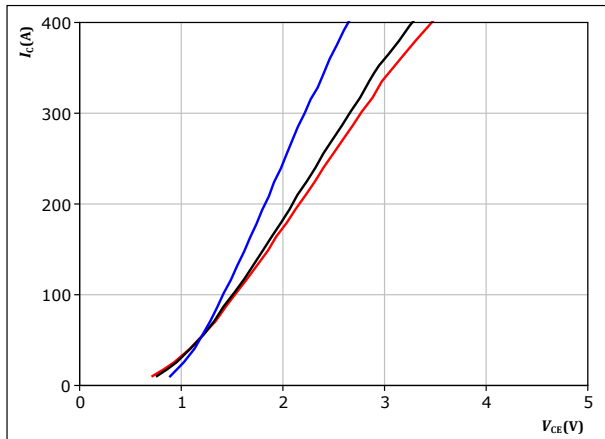
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## Inverter Switch Characteristics

figure 1. IGBT

Typical output characteristics

$$I_C = f(V_{CE})$$



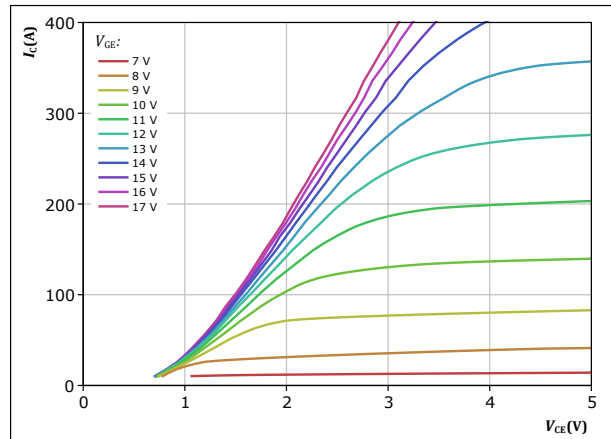
$t_p = 250 \mu s$   
 $V_{GE} = 15 V$

$T_j$ :  
— 25 °C  
— 125 °C  
— 150 °C

figure 2. IGBT

Typical output characteristics

$$I_C = f(V_{CE})$$

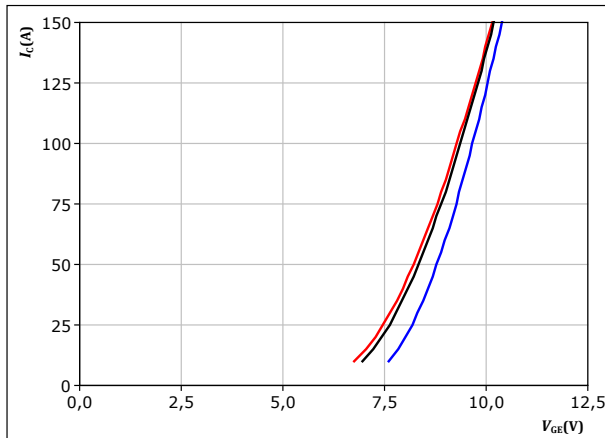


$t_p = 250 \mu s$   
 $T_j = 150 ^\circ C$   
 $V_{GE}$  from 7 V to 17 V in steps of 1 V

figure 3. IGBT

Typical transfer characteristics

$$I_C = f(V_{GE})$$



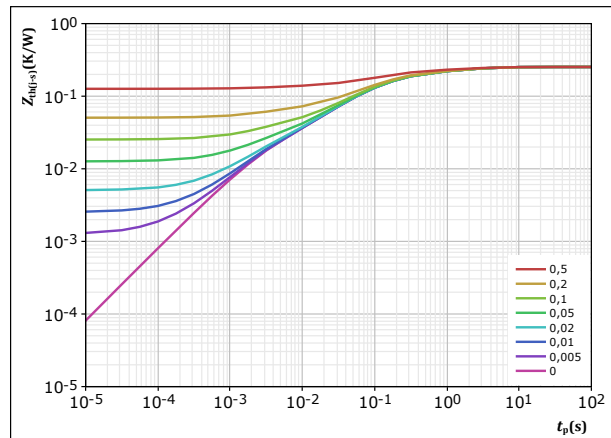
$t_p = 250 \mu s$   
 $V_{CE} = 10 V$

$T_j$ :  
— 25 °C  
— 125 °C  
— 150 °C

figure 4. IGBT

Transient thermal impedance as a function of pulse width

$$Z_{th(j-s)} = f(t_p)$$



$D = t_p / T$   
 $R_{th(j-s)} = 0,253 K/W$   
IGBT thermal model values  

$R (K/W)$	$\tau (s)$
2,70E-02	3,17E+00
4,84E-02	7,11E-01
1,14E-01	1,26E-01
4,84E-02	3,30E-02
1,46E-02	2,57E-03



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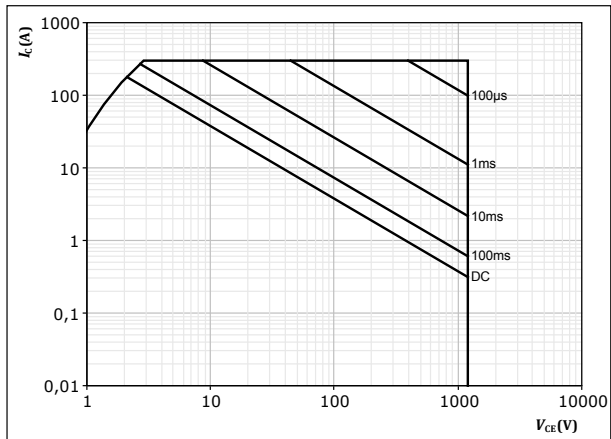
## Inverter Switch Characteristics

figure 5.

IGBT

Safe operating area

$I_C = f(V_{CE})$



$D = \text{single pulse}$

$T_s = 80 \text{ } ^\circ\text{C}$   
 $V_{GE} = 15 \text{ V}$   
 $T_j = T_{jmax}$



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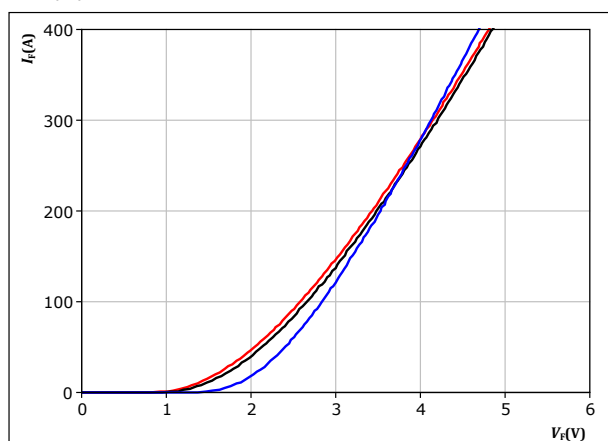
## Inverter Diode Characteristics

figure 6.

FWD

Typical forward characteristics

$$I_F = f(V_F)$$



$t_p = 250 \mu s$

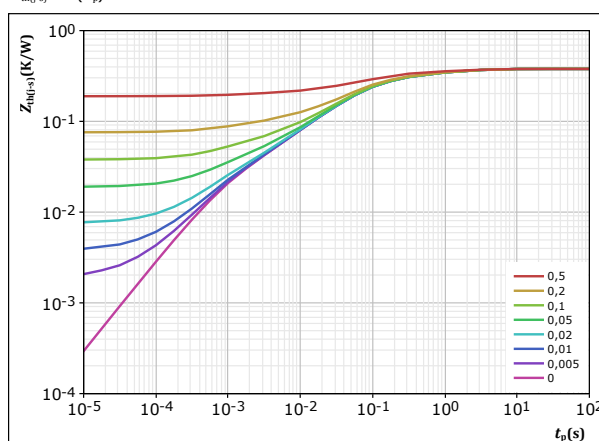
$T_j$ :  
— 25 °C  
— 125 °C  
— 150 °C

figure 7.

FWD

Transient thermal impedance as a function of pulse width

$$Z_{th(j-s)} = f(t_p)$$



$D = t_p / T$   
 $R_{th(j-s)} = 0,378 \text{ K/W}$   
FWD thermal model values  

$R \text{ (K/W)}$	$\tau \text{ (s)}$
3,49E-02	2,55E+00
7,37E-02	4,68E-01
1,99E-01	6,75E-02
5,07E-02	1,08E-02
2,05E-02	9,46E-04



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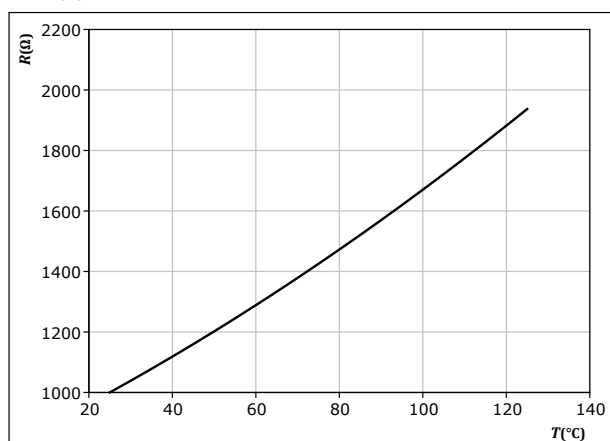
## Thermistor Characteristics

figure 8.

Thermistor

Typical PTC characteristic as function of temperature

$$R_T = f(T)$$





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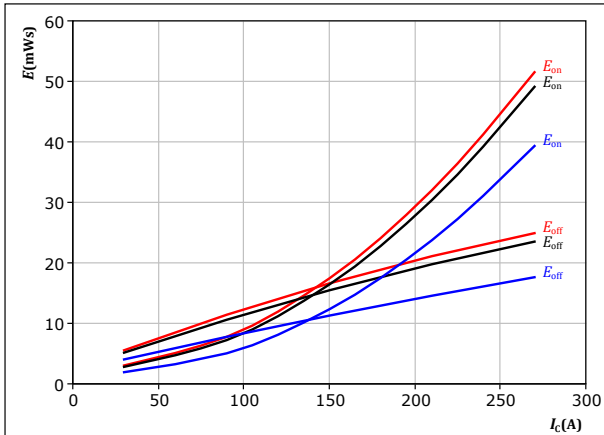
## Inverter Switching Characteristics

figure 9.

IGBT

Typical switching energy losses as a function of collector current

$$E = f(I_C)$$



With an inductive load at

$V_{CE} = 600 \text{ V}$   
 $V_{GE} = \pm 15 \text{ V}$   
 $R_{gon} = 4 \text{ } \Omega$   
 $R_{goff} = 4 \text{ } \Omega$

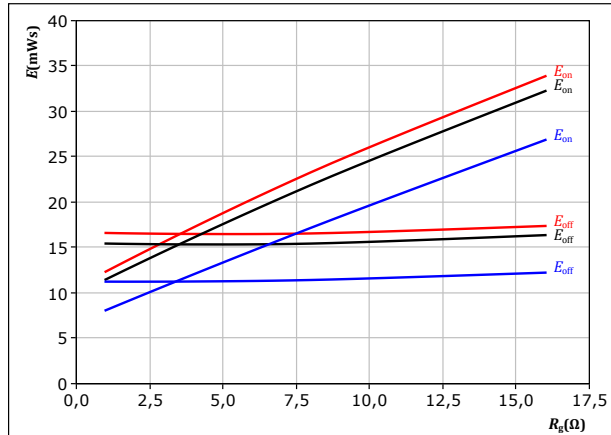
$T_j$ :  
— 25 °C  
— 125 °C  
— 150 °C

figure 10.

IGBT

Typical switching energy losses as a function of gate resistor

$$E = f(R_g)$$



With an inductive load at

$V_{CE} = 600 \text{ V}$   
 $V_{GE} = \pm 15 \text{ V}$   
 $I_C = 150 \text{ A}$

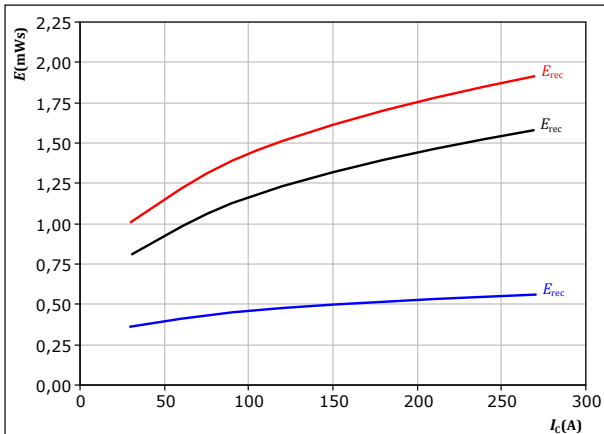
$T_j$ :  
— 25 °C  
— 125 °C  
— 150 °C

figure 11.

FWD

Typical reverse recovered energy loss as a function of collector current

$$E_{rec} = f(I_C)$$



With an inductive load at

$V_{CE} = 600 \text{ V}$   
 $V_{GE} = \pm 15 \text{ V}$   
 $R_{gon} = 4 \text{ } \Omega$

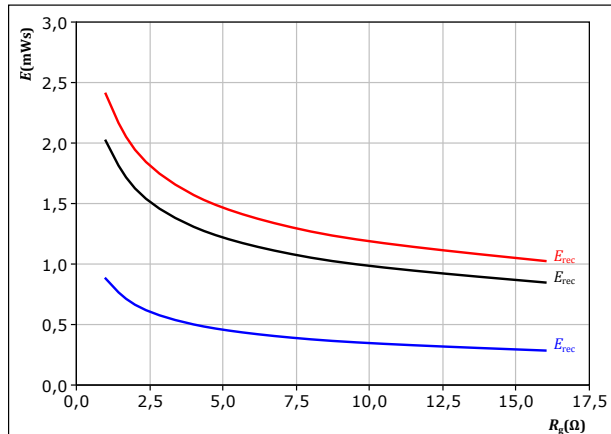
$T_j$ :  
— 25 °C  
— 125 °C  
— 150 °C

figure 12.

FWD

Typical reverse recovered energy loss as a function of gate resistor

$$E_{rec} = f(R_g)$$



With an inductive load at

$V_{CE} = 600 \text{ V}$   
 $V_{GE} = \pm 15 \text{ V}$   
 $I_C = 150 \text{ A}$

$T_j$ :  
— 25 °C  
— 125 °C  
— 150 °C



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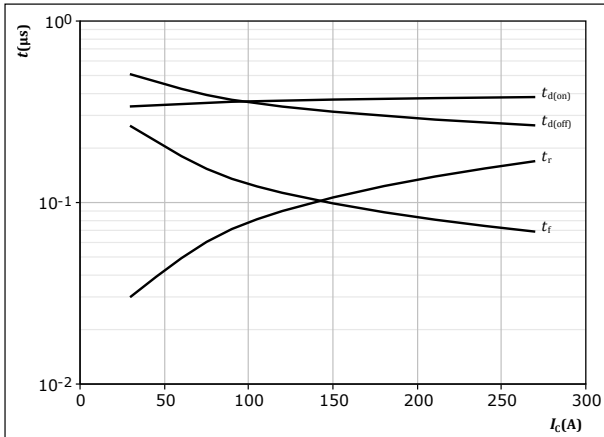
## Inverter Switching Characteristics

figure 13.

IGBT

Typical switching times as a function of collector current

$$t = f(I_c)$$



With an inductive load at

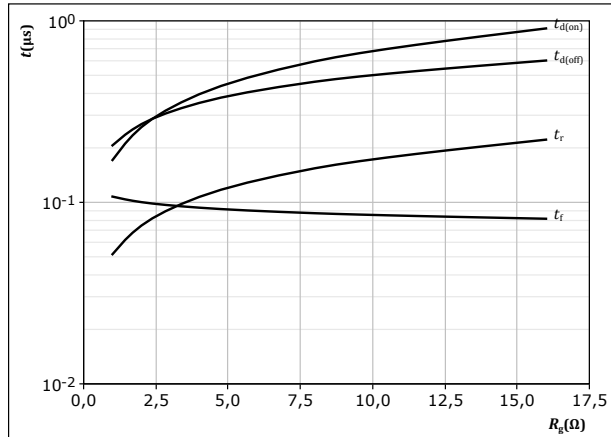
$T_j = 150$  °C  
 $V_{CE} = 600$  V  
 $V_{GE} = \pm 15$  V  
 $R_{gon} = 4$  Ω  
 $R_{goff} = 4$  Ω

figure 14.

IGBT

Typical switching times as a function of gate resistor

$$t = f(R_g)$$



With an inductive load at

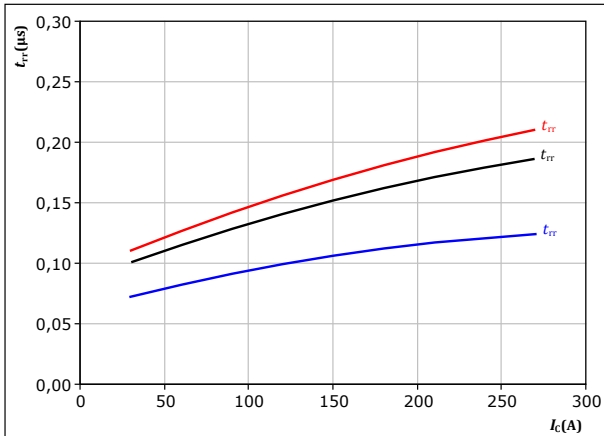
$T_j = 150$  °C  
 $V_{CE} = 600$  V  
 $V_{GE} = \pm 15$  V  
 $I_c = 150$  A

figure 15.

FWD

Typical reverse recovery time as a function of collector current

$$t_{rr} = f(I_c)$$



With an inductive load at

$V_{CE} = 600$  V  
 $V_{GE} = \pm 15$  V  
 $R_{gon} = 4$  Ω

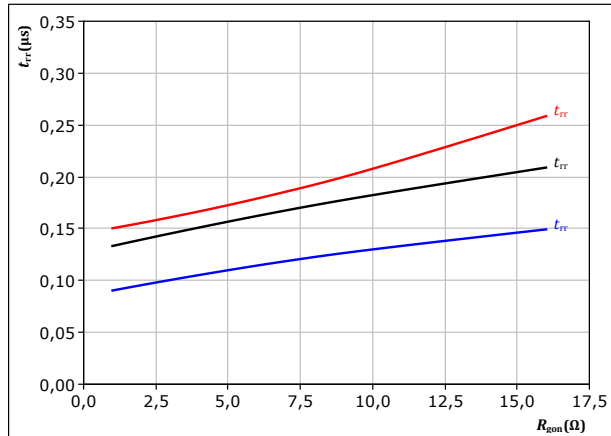
$T_j$ :  
— 25 °C  
— 125 °C  
— 150 °C

figure 16.

FWD

Typical reverse recovery time as a function of IGBT turn on gate resistor

$$t_{rr} = f(R_{gon})$$



With an inductive load at

$V_{CE} = 600$  V  
 $V_{GE} = \pm 15$  V  
 $I_c = 150$  A

$T_j$ :  
— 25 °C  
— 125 °C  
— 150 °C



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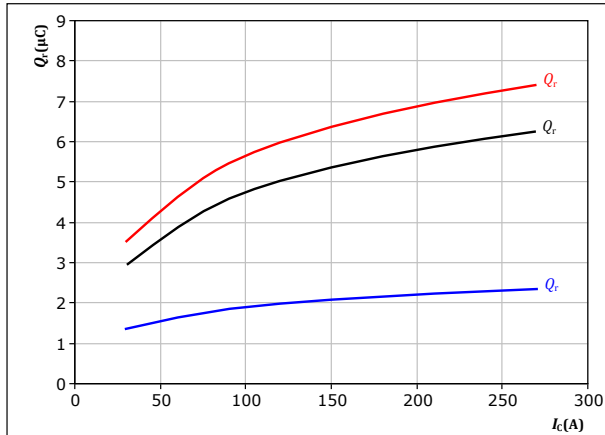
## Inverter Switching Characteristics

figure 17.

FWD

Typical recovered charge as a function of collector current

$$Q_r = f(I_c)$$



With an inductive load at

$V_{CE} = 600$  V  
 $V_{GE} = \pm 15$  V  
 $R_{gon} = 4$   $\Omega$

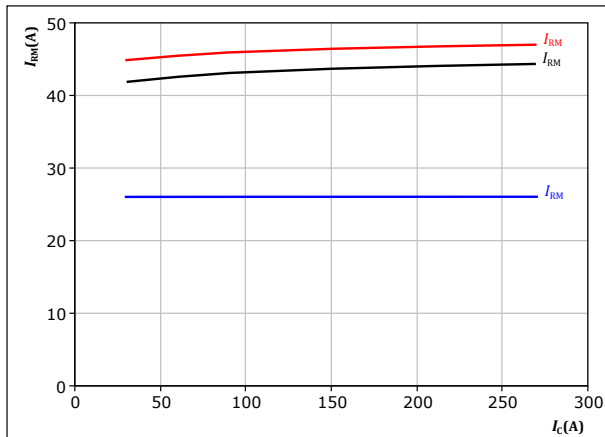
$T_j$ :  
— 25 °C  
— 125 °C  
— 150 °C

figure 19.

FWD

Typical peak reverse recovery current as a function of collector current

$$I_{RM} = f(I_c)$$



With an inductive load at

$V_{CE} = 600$  V  
 $V_{GE} = \pm 15$  V  
 $R_{gon} = 4$   $\Omega$

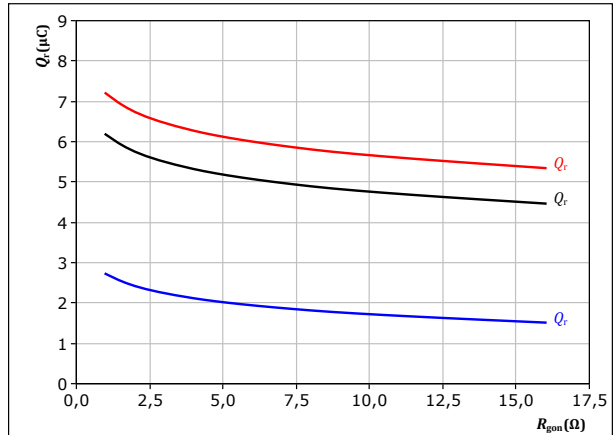
$T_j$ :  
— 25 °C  
— 125 °C  
— 150 °C

figure 18.

FWD

Typical recovered charge as a function of turn on gate resistor

$$Q_r = f(R_{gon})$$



With an inductive load at

$V_{CE} = 600$  V  
 $V_{GE} = \pm 15$  V  
 $I_c = 150$  A

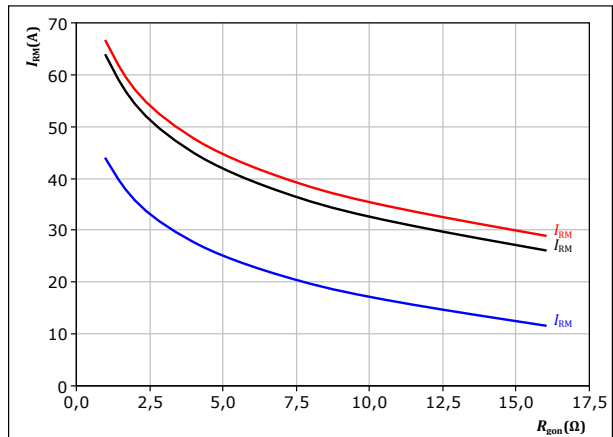
$T_j$ :  
— 25 °C  
— 125 °C  
— 150 °C

figure 20.

FWD

Typical peak reverse recovery current as a function of turn on gate resistor

$$I_{RM} = f(R_{gon})$$



With an inductive load at

$V_{CE} = 600$  V  
 $V_{GE} = \pm 15$  V  
 $I_c = 150$  A

$T_j$ :  
— 25 °C  
— 125 °C  
— 150 °C



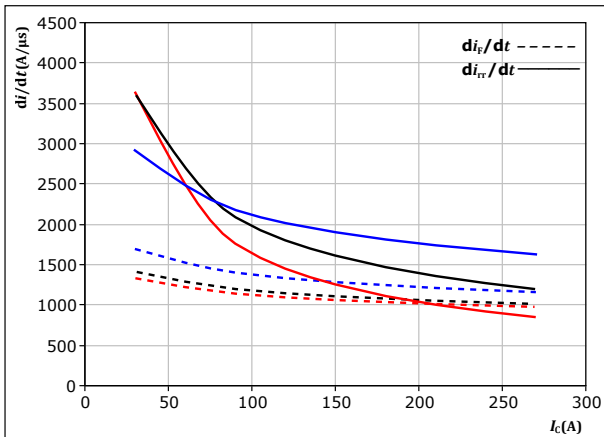
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## Inverter Switching Characteristics

figure 21. FWD

Typical rate of fall of forward and reverse recovery current as a function of collector current  
 $di_f/dt, di_r/dt = f(I_c)$



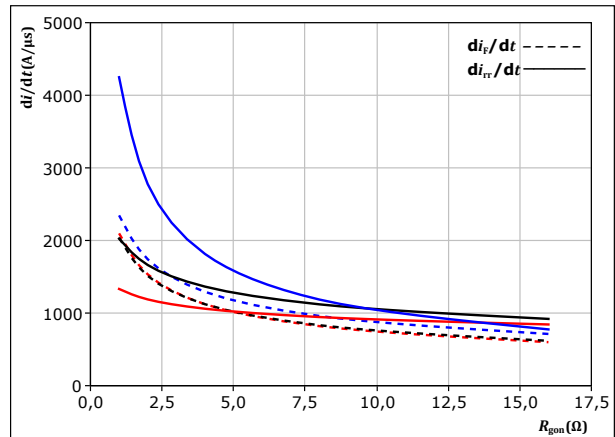
With an inductive load at

$V_{CE} = 600 \text{ V}$   
 $V_{GE} = \pm 15 \text{ V}$   
 $R_{gon} = 4 \Omega$

$T_j:$  — 25 °C  
— 125 °C  
— 150 °C

figure 22. FWD

Typical rate of fall of forward and reverse recovery current as a function of turn on gate resistor  
 $di_f/dt, di_r/dt = f(R_{gon})$



With an inductive load at

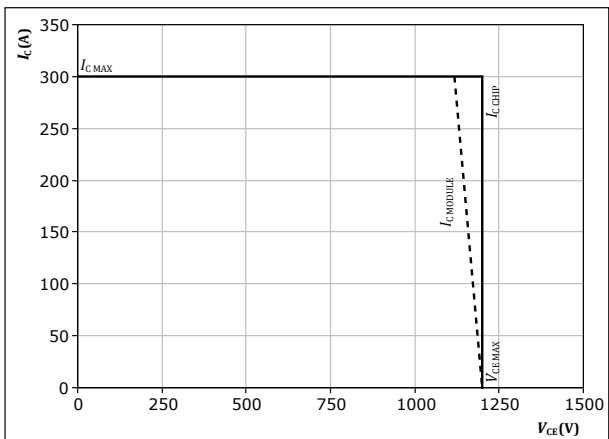
$V_{CE} = 600 \text{ V}$   
 $V_{GE} = \pm 15 \text{ V}$   
 $I_c = 150 \text{ A}$

$T_j:$  — 25 °C  
— 125 °C  
— 150 °C

figure 23. IGBT

Reverse bias safe operating area

$I_c = f(V_{CE})$



At  $T_j = 150^\circ\text{C}$   
 $R_{gon} = 4 \Omega$   
 $R_{goff} = 4 \Omega$



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## Inverter Switching Definitions

figure 24. IGBT

Turn-off Switching Waveforms & definition of  $t_{doff}$ ,  $t_{Eoff}$  ( $t_{Eoff}$  = integrating time for  $E_{off}$ )

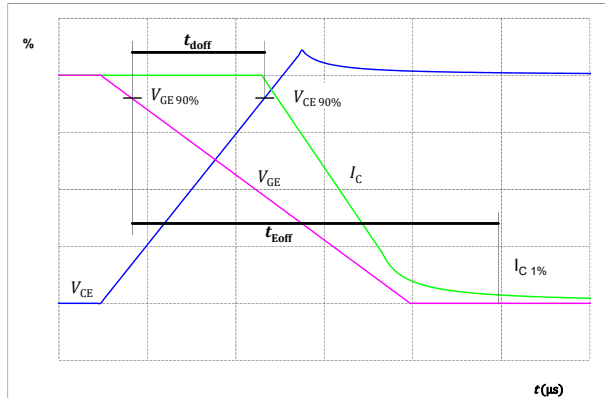


figure 25. IGBT

Turn-on Switching Waveforms & definition of  $t_{don}$ ,  $t_{Eon}$  ( $t_{Eon}$  = integrating time for  $E_{on}$ )

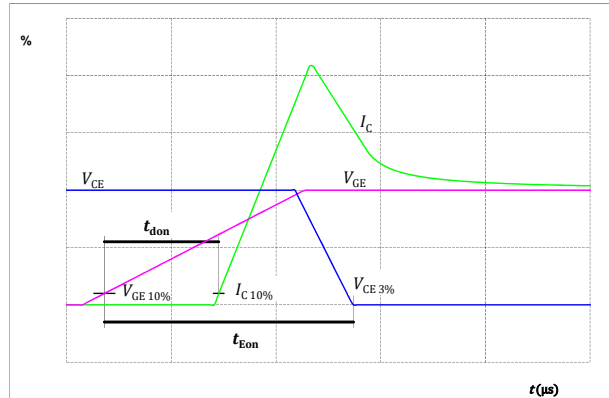


figure 26. IGBT

Turn-off Switching Waveforms & definition of  $t_f$

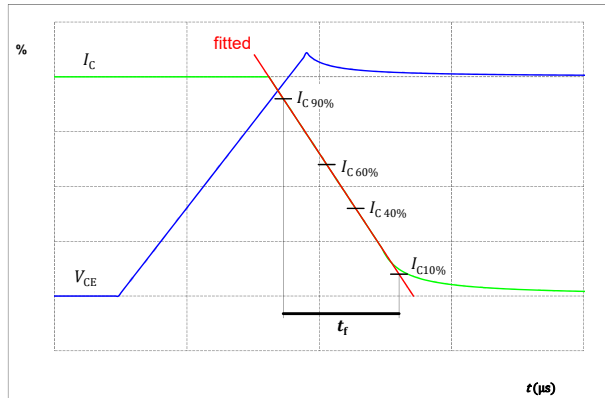
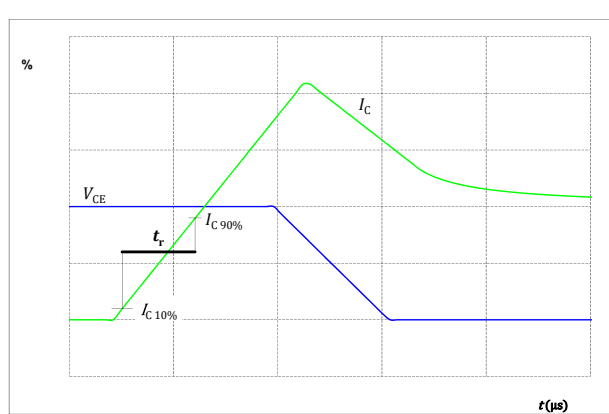


figure 27. IGBT

Turn-on Switching Waveforms & definition of  $t_r$





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## Inverter Switching Definitions

figure 28.

FWD

Turn-off Switching Waveforms & definition of  $t_{rr}$

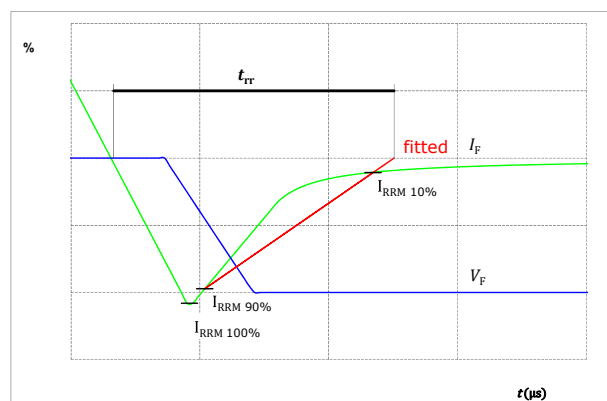
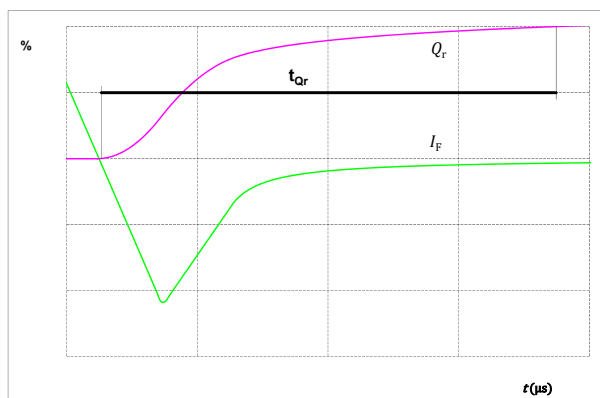


figure 29.

FWD


Turn-on Switching Waveforms & definition of  $t_{Qr}$  ( $t_{Qr}$  = integrating time for  $Q_r$ )





# Vincotech

Ordering Code	
Version	Ordering Code
With std lid (6.5mm height) + no thermal grease	80-M3126TA150M7-K829F71-/0A/
With thin lid (2.8mm height) + no thermal grease	80-M3126TA150M7-K829F71-/0B/
With std lid (6.5mm height) + thermal grease (0,8 W/mK, P12, silicone-based)	80-M3126TA150M7-K829F71-/1A/
With thin lid (2.8mm height) + thermal grease (0,8 W/mK, P12, silicone-based)	80-M3126TA150M7-K829F71-/1B/
With std lid (6.5mm height) + thermal grease (2,5 W/mK, TG20032, silicone-free)	80-M3126TA150M7-K829F71-/4A/
With thin lid (2.8mm height) + thermal grease (2,5 W/mK, TG20032, silicone-free)	80-M3126TA150M7-K829F71-/4B/
With std lid (6.5mm height) + thermal grease (2,5 W/mK, HPTP, silicone-based)	80-M3126TA150M7-K829F71-/5A/
With thin lid (2.8mm height) + thermal grease (2,5 W/mK, HPTP, silicone-based)	80-M3126TA150M7-K829F71-/5B/

Marking							
	Text	Name NN-NNNNNNNNNNNNNN- TTTTTV		Date code WWYY	UL & VIN UL VIN	Lot LLLLL	Serial SSSS
		Datamatrix	Type&Ver TTTTTV	Lot number LLLLL	Serial SSSS	Date code WWYY	

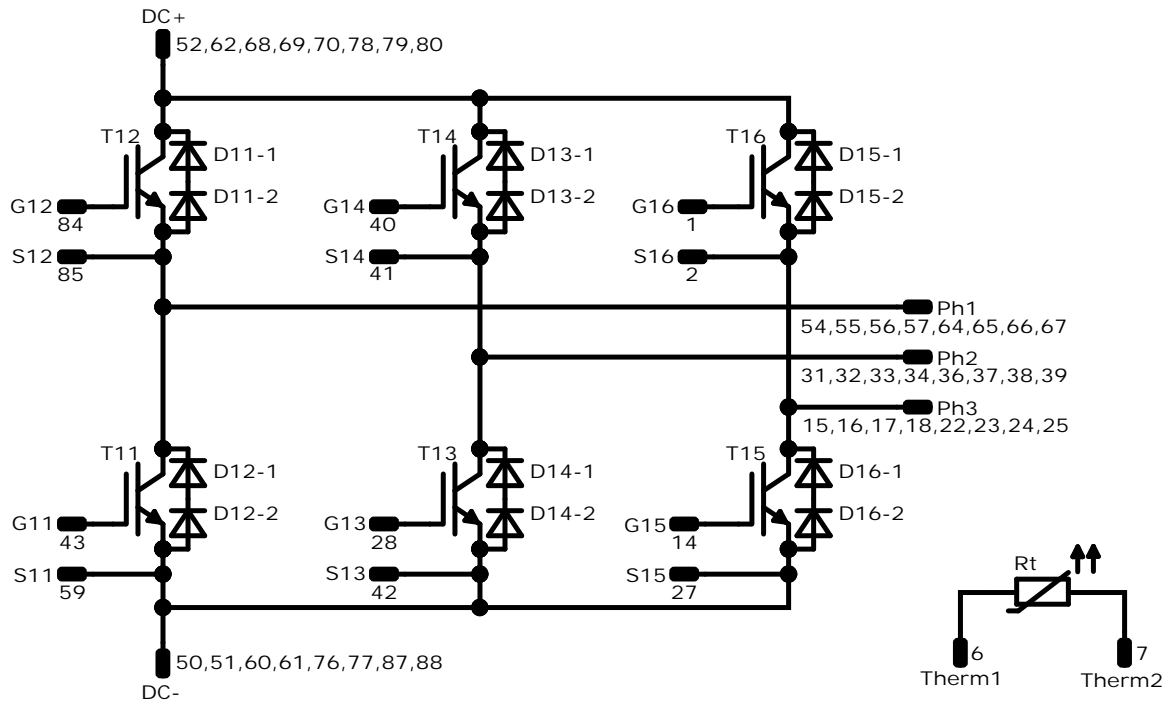
Outline						
Pin table [mm]						
Pin	X	Y	Function	45	not assembled	
1	15,83	-25,3	G16	46	not assembled	
2	15,83	-6,4	S16	47	not assembled	
3	not assembled			48	not assembled	
4	not assembled			49	not assembled	
5	not assembled			50	-35,68	22,1 DC-
6	15,83	6,4	Therm1	51	-35,68	25,3 DC-
7	15,83	15,7	Therm2	52	-36,58	-25,3 DC+
8	not assembled			53	not assembled	
9	not assembled			54	-36,58	-15,7 Ph1
10	not assembled			55	-36,58	-12,5 Ph1
11	not assembled			56	-36,58	-9,3 Ph1
12	not assembled			57	-36,58	-6,1 Ph1
13	not assembled			58	not assembled	
14	8,13	25,3	G15	59	-39,32	18,9 S11
15	1,82	-15,38	Ph3	60	-39,32	22,1 DC-
16	1,82	-12,18	Ph3	61	-39,32	25,3 DC-
17	1,82	-8,98	Ph3	62	-40,22	-25,3 DC+
18	1,82	-5,79	Ph3	63	not assembled	
19	not assembled			64	-40,22	-15,7 Ph1
20	not assembled			65	-40,22	-12,5 Ph1
21	not assembled			66	-40,22	-9,3 Ph1
22	-1,82	-15,38	Ph3	67	-40,22	-6,09 Ph1
23	-1,82	-12,18	Ph3	68	-50,18	-25,3 DC+
24	-1,82	-8,98	Ph3	69	-50,18	-22,1 DC+
25	-1,82	-5,79	Ph3	70	-50,18	-18,9 DC+
26	not assembled			71	not assembled	
27	-7,27	22,1	S15	72	not assembled	
28	-7,27	25,3	G13	73	not assembled	
29	not assembled			74	not assembled	
30	not assembled			75	not assembled	
31	-16,05	-15,02	Ph2	76	-50,18	22,1 DC-
32	-16,05	-11,82	Ph2	77	-50,18	25,3 DC-
33	-16,05	-8,63	Ph2	78	-53,82	-25,3 DC+
34	-16,05	-5,42	Ph2	79	-53,82	-22,1 DC+
35	not assembled			80	-53,82	-18,9 DC+
36	-19,7	-15,02	Ph2	81	not assembled	
37	-19,7	-11,82	Ph2	82	not assembled	
38	-19,7	-8,62	Ph2	83	not assembled	
39	-19,7	-5,42	Ph2	84	-53,82	3,1 G12
40	-22,26	-1	G14	85	-53,82	6,3 S12
41	-22,26	2,2	S14	86	not assembled	
42	-22,67	22,1	S13	87	-53,82	22,1 DC-
43	-22,67	25,3	G11	88	-53,82	25,3 DC-
44	not assembled					



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Pinout



Identification

ID	Component	Voltage	Current	Function	Comment
T11, T12, T13, T14, T15, T16	IGBT	1200 V	150 A	Inverter Switch	
D11, D12, D13, D14, D15, D16	FWD	1300 V	150 A	Inverter Diode	
Rt	Thermistor			Thermistor	



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datasheet

Packaging instruction				
Standard packaging quantity (SPQ) 48	>SPQ	Standard	<SPQ	Sample

Handling instruction
Handling instructions for MiniSKiiP® 3 packages see vincotech.com website.

Package data
Package data for MiniSKiiP® 3 packages see vincotech.com website.

Vincotech thermistor reference
See Vincotech thermistor reference table at vincotech.com website.

UL recognition and file number
This device is certified according to UL 1557 standard, UL file number E192116. For more information see vincotech.com website.



Document No.:	Date:	Modification:	Pages
80-M3126TA150M7-K829F71-D1-14	19 Mar. 2021		

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